

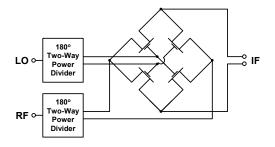
PE4128

Product Description

The PE4128 is a high linearity, passive Quad MOSFET Mixer for WCS and 2.4 GHz ISM applications exhibiting high dynamic range performance over an LO drive range of up to +20 dBm. This mixer integrates passive matching networks to provide single ended interfaces for the RF and LO ports, eliminating the need for external RF baluns or matching networks. The PE4128 is optimized for low-side injection using a 300-360 MHz nominal IF frequency, and is also suitable for use in upconversion applications.

The PE4128 is manufactured in Peregrine's patented Ultra Thin Silicon (UTSi®) CMOS process, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Schematic Diagram



High Linearity Quad MOSFET Mixer for WCS and 2.4 GHz ISM Band Applications

Features

- Integrated, single-ended RF & LO interfaces
- High linearity: IIP3>+30 dBm,
 2.28 2.5 GHz (+17 dBm LO)
- Low conversion loss: 8 dB max (+17 dBm LO)
- High isolation: typical LO-IF at 38 dB / LO-RF at 34 dB
- Designed for low-side LO injection

Figure 2. Package Type

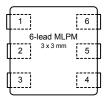


Table 1. Electrical Specifications @ +25 °C ($Z_S = Z_L = 50 \Omega$)

Parameter	Minimum	Typical	Maximum	Units
Frequency Range:				
LO	1920		2200	MHz
RF	2280		2500	MHz
IF*		300-360		MHz
Conversion Loss**		7.5		dB
Isolation:				dB
LO-RF		34		dB
LO-IF		38		dB
Input IP3		30		dBm
Input 1 dB Compression		20		dBm

^{*}An IF frequency range of 300-360 MHz is a nominal frequency. The IF frequency can be specified by the user as long as the RF and LO frequencies are within the specified maximum and minimum limits.

Test conditions unless otherwise noted: LO input drive = 17 dBm.

^{**}Conversion Loss includes loss of IF transformer (M/A COM ETC1-1-13, nominal loss of 0.7dB at 70 MHz).



Figure 3. Pin Configuration

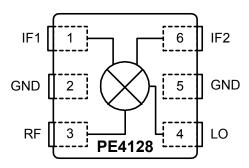


Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	IF1	IF differential output
2	GND	Ground connections for Mixer. Traces should be physically short and connect immediately to ground plane for best performance. The exposed solder pad must also be soldered to the ground plane for best performance.
3	RF	RF Input
4	LO	LO Input
5	GND	Ground connections for Mixer. Traces should be physically short and connect immediately to ground plane for best performance. The exposed solder pad must also be soldered to the ground plane for best performance.
6	IF2	IF differential output

Table 3. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
T _{ST}	Storage temperature range	-65	150	°C
T_OP	Operating temperature range	-40	85	°C
P _{LO}	LO input power		20	dBm
P_RF	RF input power		16	dBm
V_{ESD}	ESD Sensitive Device		200	V

Electrostatic Discharge (ESD) Precautions

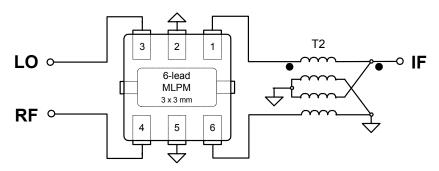
When handling this UTSi device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified.

Latch-Up Avoidance

Unlike conventional CMOS devices, UTSi CMOS devices are immune to latch-up.



Figure 4. Typical Application Schematic



T2 M/A-Com E-Series RF 4:1 Transformer 2.0 – 1000 MHz ETK4-2T

Figure 5. Evaluation Board Layout

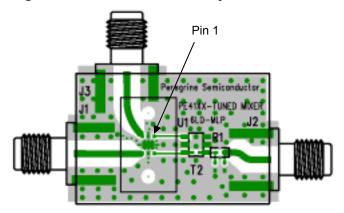
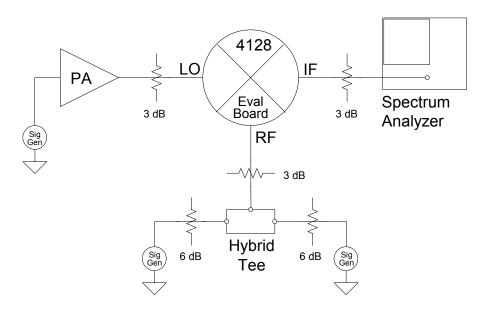


Table 4. Bill of Materials

Reference	Value / Description	
T2	M/A Com ETK4-2T	
R1	Ω0	
U1	PE4128 MLP Mixer	
J1, J2, J3	SMA Connector	

Figure 6. Evaluation Board Testing Block Diagram, 2-Tone Setup





Typical Performance Plots @ +25 °C

Figure 7. Conversion Loss

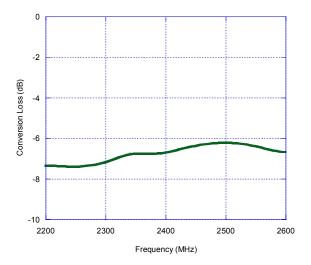


Figure 8. Input 1dB Compression

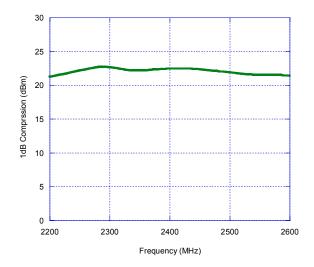


Figure 9. Input IP3

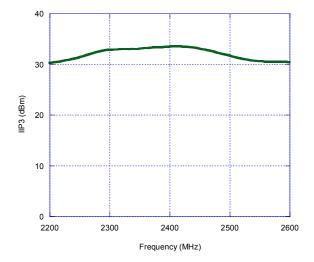




Figure 10. Package Drawings

6-lead MLPM

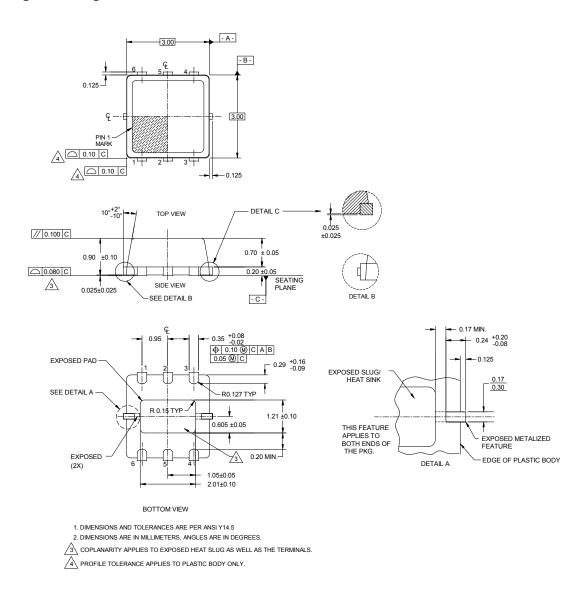


Table 5. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
4128-01	4128	PE4128-06MLP3x3-12800F	6-lead 3x3 MLPM	12800 units / Canister
4128-02	4128	PE4128-06MLP3x3-3000C	6-lead 3x3 MLPM	3000 units / T&R
4128-00	PE4128-EK	PE4128-06 MLP3x3-EK	Evaluation Board	1 / Box

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Data Sheet Identification

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